

FDD18N20LZ

N-Channel MOSFET 200V Logic, 16A, 0.125Ω

Features

- $R_{DS(on)} = 0.125\Omega$ (Max.) @ $V_{GS} = 10V$, $I_D = 8A$
- Low Gate Charge
- Low C_{rss}
- Fast Switching
- 100% Avalanche Tested
- Improved dv/dt Capability
- RoHS Compliant



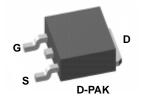


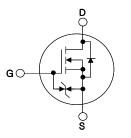
FDD18N20LZ N-Channel MOSFET

Description

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.

This advance technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for high efficient switching mode power supplies and active power factor correction.





MOSFET Maximum Ratings $T_C = 25^{\circ}C$ unless otherwise noted*

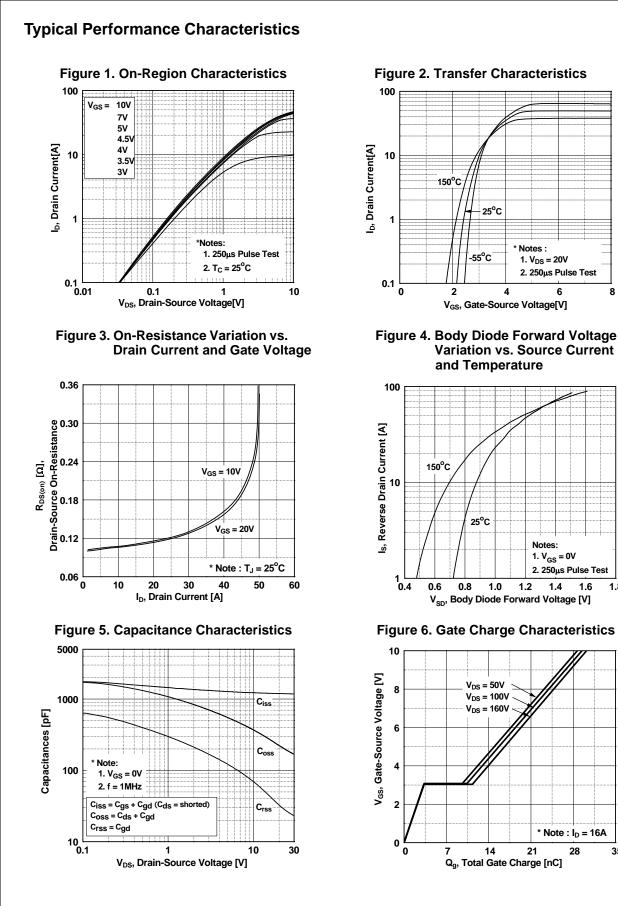
Symbol	Parameter			FDD18N20LZ	Units
V _{DSS}	Drain to Source Voltage			200	V
V _{GSS}	Gate to Source Voltage			±20	V
ID	Drain Current	-Continuous ($T_C = 25^{\circ}C$)		16	— A
		-Continuous ($T_C = 100^{\circ}C$)		9.6	
DM	Drain Current	- Pulsed	(Note 1)	64	Α
E _{AS}	Single Pulsed Avalanche Energy		(Note 2)	320	mJ
AR	Avalanche Current		(Note 1)	16	Α
E _{AR}	Repetitive Avalanche Energy		(Note 1)	8.9	mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	10	V/ns
P _D	Dower Dissinction	$(T_{C} = 25^{\circ}C)$		89	W
	Power Dissipation	- Derate above 25°C		0.7	W/ºC
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C

Thermal Characteristics

Symbol	Parameter	FDD18N20LZ	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.4	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	83	°C/W

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S				Quantity 2500	
S					
	Min.	Тур.	Max.	Units	
= 25°C	200	-	-	V	
o 25ºC	-	0.2	-	V/ºC	
	-	-	1	μA	
$V_{DS} = 160V, T_{C} = 125^{\circ}C$		-	10	μΑ	
	-	-	±10	μA	
	1.0	-	2.5	V	
	-	0.10	0.125	0	
	-	0.11	0.13	Ω	
(Note 4)	-	11	-	S	
V _{DS} = 25V, V _{GS} = 0V f = 1MHz		1185	1575	pF	
		190	255	pF	
		25	40	pF	
	-	30	40	nC	
	-	3.5	-	nC	
V _{GS} = 10V (Note 4, 5)		8.5	-	nC	
(14010 4, 0)					
		15	10		
-	-	15	40	ns	
$V_{DD} = 100V, I_D = 16A$ $V_{GS} = 10V, R_G = 25\Omega$		20	50	ns	
	-	135	280	ns	
(Note 4, 5)	-	50	110	ns	
	-	-	16	Α	
	-	-	64	Α	
	-	-	1.4	V	
$V_{GS} = 0V, I_{SD} = 4A$ $dI_F/dt = 100A/\mu s \qquad (Note 4)$		105	-	ns	
		0.4	-	μC	
	(Note 4)	- - -	 105	64 1.4 - 105 -	



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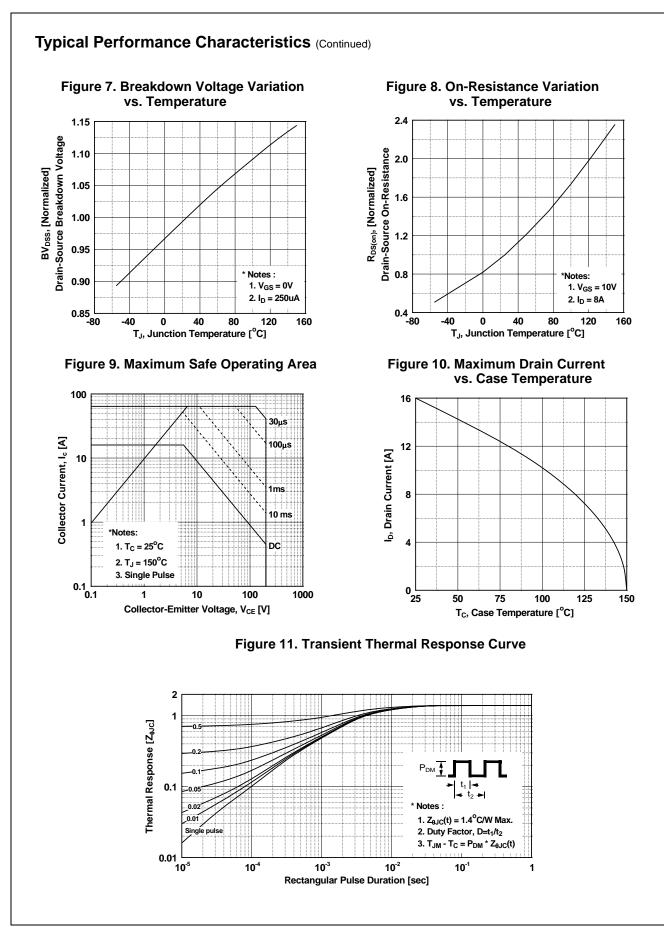
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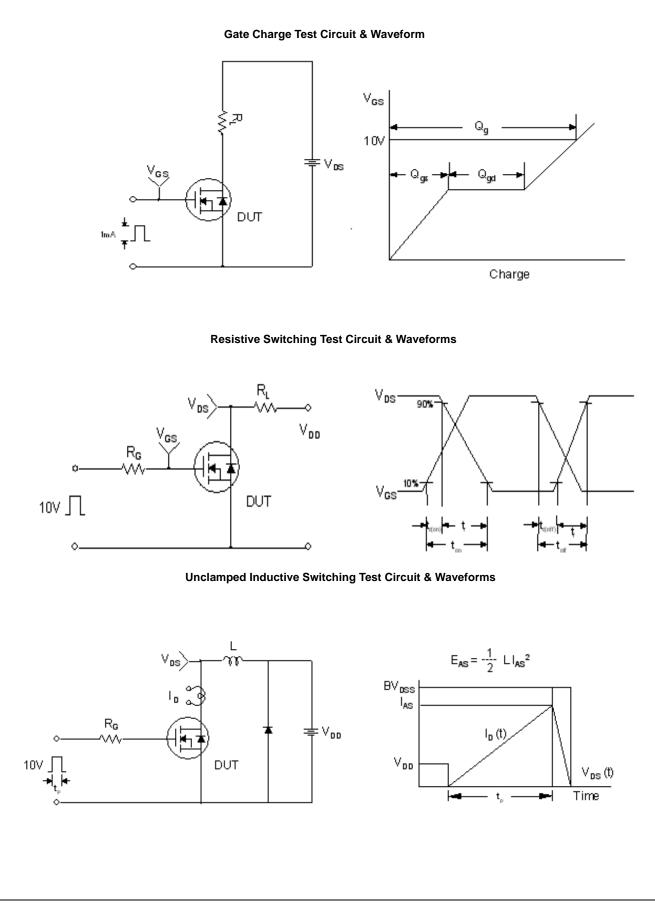
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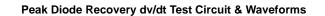
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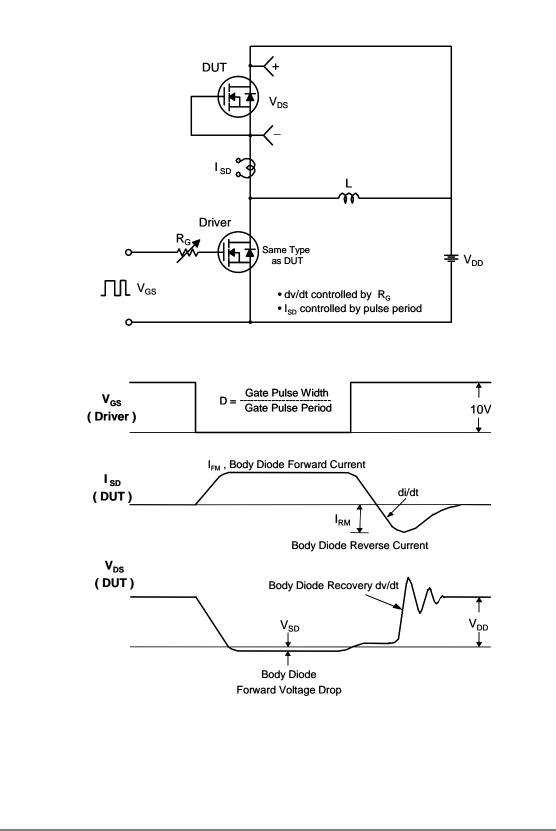


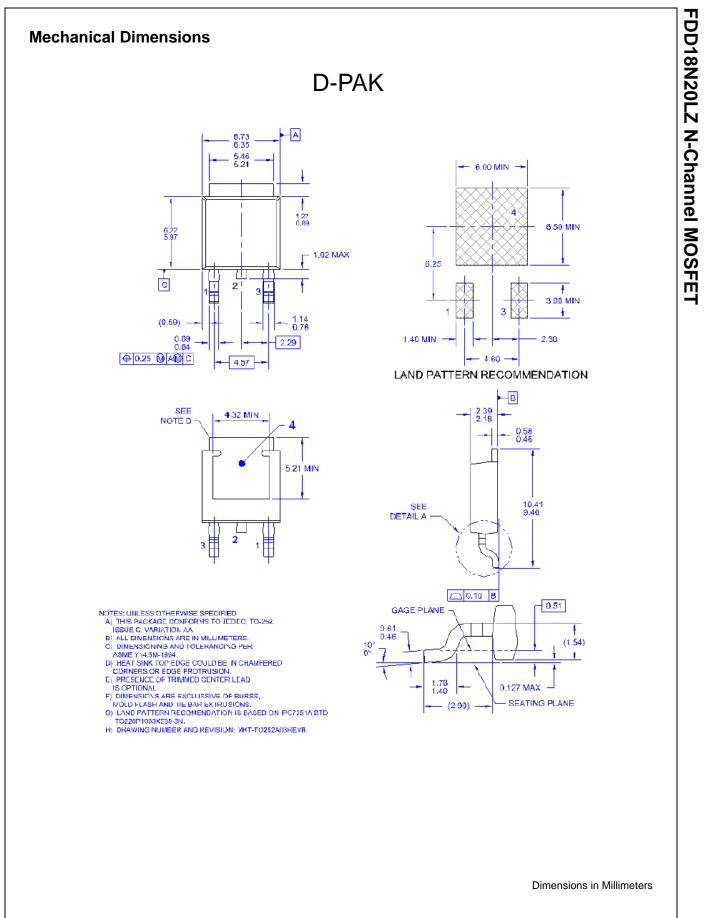
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